



30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

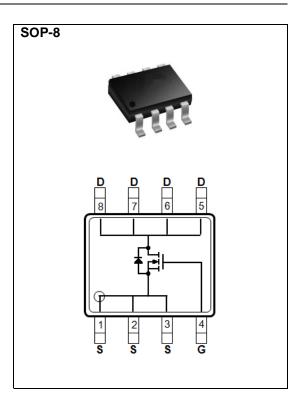
15 A

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_{D}@10A<6m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@5A<9m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

Mechanical Data

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	30	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _A =25°C		15	А	
	T _A =70°C	l _D	12		
Pulsed Drain Current (Note 1)		I _{DM}	60	А	
Power Dissipation	T _A =25°C		1.7	W	
	T _A =70°C	P _D	1.1		
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 5)		$R_{\scriptscriptstyle{\theta JA}}$	73.5	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1.0	1.6	2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =10A	-	5.0	6	mΩ	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V,I _D =5A	-	6.6	9	mΩ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1.0	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 6)							
Total Gate Charge	Q_g	V _{DS} =15V, I _D =20A, V _{GS} =4.5V (Note 1,2)	-	12	-	nC	
Gate-Source Charge	Q_gs		-	3.8	-		
Gate-Drain Charge	Q_gd	V _{GS} =4.5 V	-	4.3	-		
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V,	-	1323	-	pF	
Output Capacitance	Coss		-	219	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	136	-		
Turn-On Delay Time	td _(on)	$V_{DS}\text{=}15\text{V}, RL\text{=}1\Omega, \\ V_{GS}\text{=}10\text{V}, R_{G}\text{=}3.3\Omega \\ \text{(Note 2,3)}$	-	5.0	-	ns	
Turn-On Rise Time	tr		-	42	-		
Turn-Off Delay Time	td _(off)		-	36	-		
Turn-Off Fall Time	tf		-	5.5	-		
Drain-Source Diode							
Maximum Continuous Drain-Source			-	-	15	Α	
Diode Forward Current	I _S						
Diode Forward Voltage	V_{SD}	I _S =1.0A, V _{GS} =0V	-	0.83	1	V	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

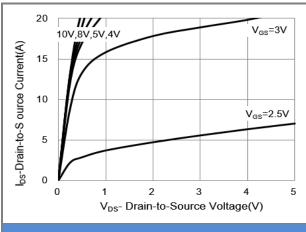


Fig.1 On-Region Characteristics

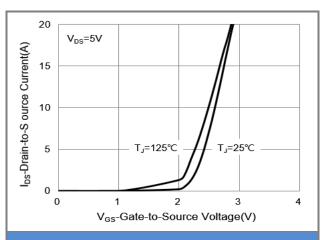


Fig.2 Transfer Characteristics

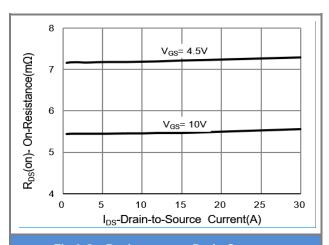


Fig.3 On-Resistance vs. Drain Current

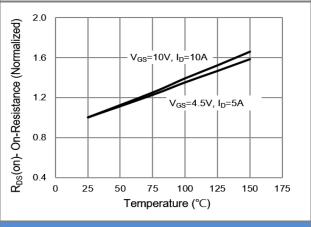


Fig.4 On-Resistance vs. Junction temperature

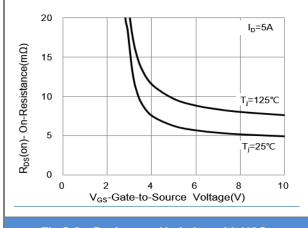


Fig.5 On-Resistance Variation with VGS.

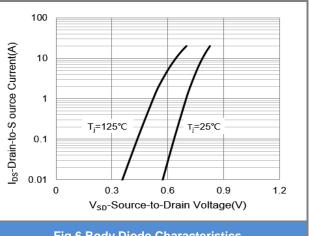


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

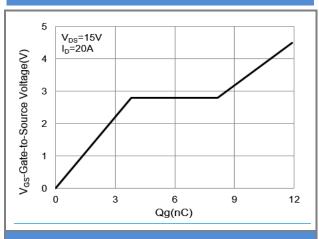


Fig.7 Gate-Charge Characteristics

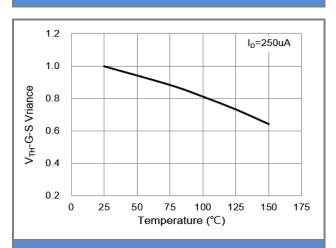


Fig.9 Threshold Voltage Variation with Temperature.

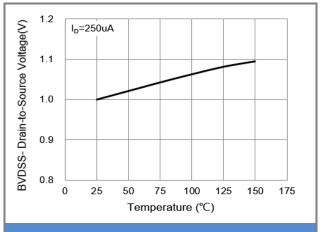


Fig.8 Breakdown Voltage Variation vs. Temperature

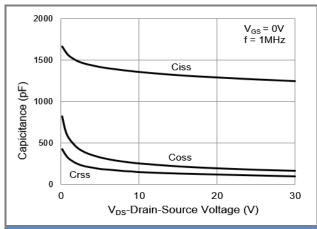


Fig.10 Capacitance vs. Drain-Source Voltage.

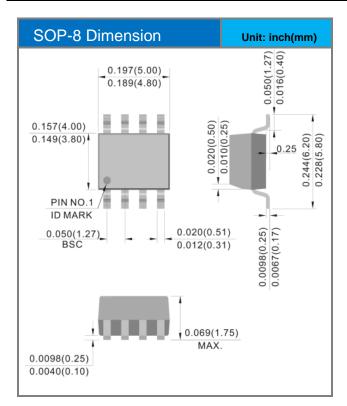


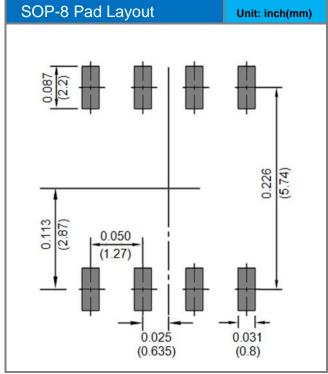


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJL9414_R2_00001	SOP-8	2.5K pcs / 13" reel	L9414	Halogen free

Packaging Information & Mounting Pad Layout









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